

INFORMATION DISCLOSURE CITATION IN AN APPLICATION (PTO-1449)	ATTY. DOCKET NO. 4590-421	U.S. APPLICATION NO. Not yet assigned 202938923
	APPLICANT Frederic NGUYEN VAN DAU	
	FILING DATE herewith	GROUP 2826

U.S. PATENT DOCUMENTS


EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
BL	6,069,820 A	2000-05-30	Kishi Tatsuya et al			
BL	2003/214004 A1	2003-11-20	Sato Rie et al			
BL	2003/122208 A1	2003-07-03	Sato et al			

FOREIGN PATENT DOCUMENTS

EXAMINER'S INITIALS	PATENT NO.	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						Yes	No
BL	2002 305335A	2003-02-05	JP				
BL	2002 329902 A	2000-11-21	JP				

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

BL	Dijken Van S et al: "Room temperature operation of a high output current magnetic tunnel transistor" Applied physics letters, American Institute of Physics, NY May 6, 2002 pages 3364-3366
BL	Monsma D J et al: "Perpendicular Hot Electron Spin-Valve Effect in a New Magnetic Field Sensor: The Spin-Valve Transistor" Physical Review Letters, NY June 26, 1995 pages 5260-5263
BL	Kumar P S et al: "The spin-valve transistor" Journal of Physics D (Applied physics) November 21, 2000 IOP Publishing, UK
BL	Sato R et al: "Spin-Valve Transistor Formed on Gaas (001) Substrate" IEEE Transactions on Magnetics, IEEE Inc. NY US September 2002 pages 2863-2868
BL	M. Guth et al "Tunnel magnetoresistance in magnetic tunnel junctions with a ZnS barrier" Applied Physics Letters May 28, 2001
BL	P. Rottlander et al "Tantalum oxide as an alternative low height tunnel barrier in magnetic junctions" Applied Physics Letters May 21, 2001

EXAMINER 	DATE CONSIDERED 4/27/2006
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.